

2811

IR-1677 (2-1984)  
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Zhijun Qu et al.

Serial No.: 09/329,156

Filed: June 9, 1999

For: DUAL EPITAXIAL LAYER FOR HIGH VOLTAGE VERTICAL CONDUCTION POWER MOSFET DEVICES

Asst. Commissioner for Patents

Washington, D.C. 20231



Date: March 27, 2001

Group Art Unit: 2811

Examiner: S. Hu

#12e  
Jm  
4/5/01

AMENDMENT/SUBMISSION

This is a response to the Office Action mailed February 28, 2001 in the above-identified application. Reconsideration of the application is respectfully requested.

FEE CALCULATION

Any additional fee required has been calculated as follows:

\_\_\_\_\_ If checked, "Small Entity" status is claimed.

	NO. CLAIMS		HIGHEST NO.				RATE	ADDIT. FEE
	AFTER	AMENDMENT	PREVIOUSLY	PAID FOR	EXTRA PRESENT			
TOTAL	9	MINUS	20	* =	0	X	(\$9 SE or \$18)	\$
INDEP.	1	MINUS	3	** =	0	X	(\$40 SE or \$80)	\$
FIRST PRESENTATION OF MULTIPLE DEPENDENT CLAIM						X	(\$135 SE or \$270)	\$
* not less than 20 ** not less than 3								TOTAL \$ -0-

If any additional payment is required, a check which includes the calculated fee of \$ \_\_\_\_\_ (OFGS Check No. \_\_\_\_\_) is attached.

In the event the actual fee is greater than the payment submitted or is inadvertently not enclosed or if any additional fee during the prosecution of this application is not paid, the Patent Office is authorized to charge the underpayment to Deposit Account No. 15-0700.